



## 2N65

Power MOSFET

### 2A, 650V N-CHANNEL POWER MOSFET

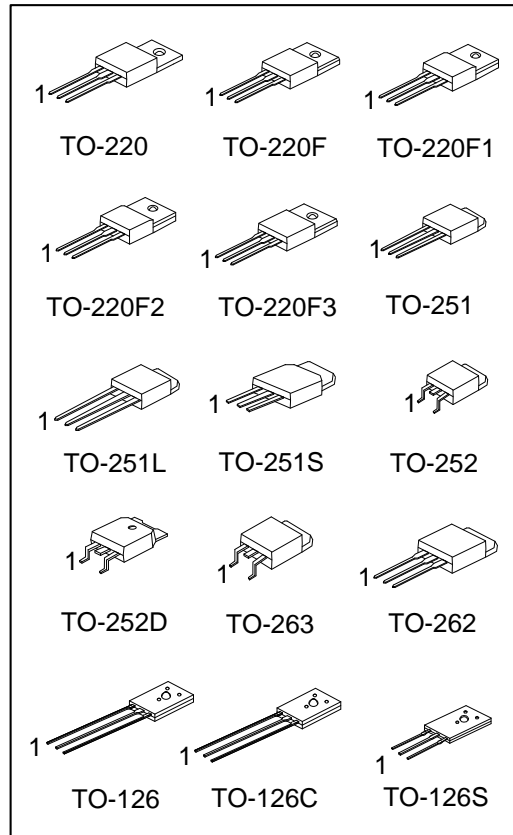
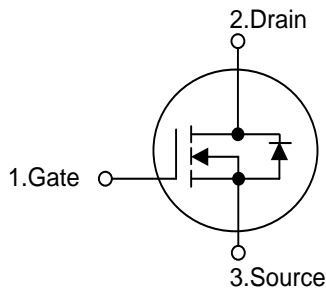
#### DESCRIPTION

The UTC 2N65 is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.

#### FEATURES

- \*  $R_{DS(ON)} \leq 5.0 \Omega @ V_{GS} = 10V, I_D = 1.0A$
- \* Ultra Low gate charge (typical 45nC)
- \* Low reverse transfer capacitance ( $C_{RSS} =$  typical 9 pF)
- \* Fast switching capability
- \* Avalanche energy specified
- \* Improved dv/dt capability, high ruggedness

#### SYMBOL



## ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2N65L-TA3-T	2N65G-TA3-T	TO-220	G	D	S	Tube
2N65L-TF1-T	2N65G-TF1-T	TO-220F1	G	D	S	Tube
2N65L-TF2-T	2N65G-TF2-T	TO-220F2	G	D	S	Tube
2N65L-TF3-T	2N65G-TF3-T	TO-220F	G	D	S	Tube
2N65L-TF3T-T	2N65G-TF3T-T	TO-220F3	G	D	S	Tube
2N65L-TM3-T	2N65G-TM3-T	TO-251	G	D	S	Tube
2N65L-TMA-T	2N65G-TMA-T	TO-251L	G	D	S	Tube
2N65L-TMS-T	2N65G-TMS-T	TO-251S	G	D	S	Tube
2N65L-TN3-R	2N65G-TN3-R	TO-252	G	D	S	Tape Reel
2N65L-TND-R	2N65G-TND-R	TO-252D	G	D	S	Tape Reel
2N65L-T2Q-T	2N65G-T2Q-T	TO-262	G	D	S	Tube
2N65L-TQ2-T	2N65G-TQ2-T	TO-263	G	D	S	Tube
2N65L-TQ2-R	2N65G-TQ2-R	TO-263	G	D	S	Tape Reel
2N65L-T60-K	2N65G-T60-K	TO-126	G	D	S	Bulk
2N65L-T6C-K	2N65G-T6C-K	TO-126C	G	D	S	Bulk
2N65L-T6S-K	2N65G-T6S-K	TO-126S	G	D	S	Bulk

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>2N65G-TA3-T</p> <p>(1) Packing Type (2) Package Type (3) Green Package</p>	<p>(1) T: Tube, R: Tape Reel, K: Bulk (2) TA3: TO-220, TF1: TO-220F1, TF2: TO-220F2, TF3: TO-220F, TF3T: TO-220F3, TM3: TO-251, TMA: TO-251L, TMS: TO-251S, TN3: TO-252, TND: TO-252D, T2Q: TO-262, TQ2: TO-263 T60: TO-126, T6C: TO-126C, T6S: TO-126S (3) G: Halogen Free and Lead Free, L: Lead Free</p>
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## MARKING

PACKAGE	MARKING
TO-220 TO-220F TO-220F1 TO-220F2 TO-220F3 TO-251 TO-251L TO-251S TO-252D TO-252 TO-262 TO-263	<p>UTC 2N65 Lot Code Date Code L: Lead Free G: Halogen Free</p>
TO-126 TO-126C TO-126S	<p>UTC 2N65 Date Code L: Lead Free G: Halogen Free</p>

■ **ABSOLUTE MAXIMUM RATINGS** ( $T_C = 25^\circ\text{C}$ , unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{DSS}$	650	V
Gate-Source Voltage		$V_{GSS}$	$\pm 30$	V
Avalanche Current (Note 2)		$I_{AR}$	2.0	A
Drain Current	Continuous	$I_D$	2.0	A
	Pulsed (Note 2)	$I_{DM}$	8.0	A
Avalanche Energy	Single Pulsed (Note 3)	$E_{AS}$	140	mJ
	Repetitive (Note 2)	$E_{AR}$	4.5	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.5	V/ns
Power Dissipation	TO-220/TO-262 TO-263	$P_D$	40	W
	TO-220F/TO-220F1 TO-220F3		21	W
	TO-220F2		23	W
	TO-251/TO-251L TO-251S/TO-252 TO-252D		28	W
	TO-126/TO-126C TO-126S		12.5	W
Junction Temperature		$T_J$	+150	$^\circ\text{C}$
Operating Temperature		$T_{OPR}$	-55 ~ +150	$^\circ\text{C}$
Storage Temperature		$T_{STG}$	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by  $T_J$ .

3.  $L=64\text{mH}$ ,  $I_{AS}=2.0\text{A}$ ,  $V_{DD}=50\text{V}$ ,  $R_G=25\Omega$ , Starting  $T_J = 25^\circ\text{C}$

4.  $I_{SD}\leq 2.4\text{A}$ ,  $di/dt\leq 200\text{A}/\mu\text{s}$ ,  $V_{DD}\leq BV_{DSS}$ , Starting  $T_J = 25^\circ\text{C}$

■ **THERMAL DATA**

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-220F TO-220F1/TO-220F2 TO-220F3/TO-262 TO-263	$\theta_{JA}$	62.5	$^\circ\text{C}/\text{W}$
	TO-251/TO-251L TO-251S/TO-252 TO-252D		110	$^\circ\text{C}/\text{W}$
	TO-126/TO-126C TO-126S		132	$^\circ\text{C}/\text{W}$
Junction to Case	TO-220/TO-262 TO-263	$\theta_{JC}$	3.13	$^\circ\text{C}/\text{W}$
	TO-220F/TO-220F1 TO-220F3		5.95	$^\circ\text{C}/\text{W}$
	TO-220F2		5.43	$^\circ\text{C}/\text{W}$
	TO-251/TO-251L TO-251S/TO-252 TO-252D		4.53	$^\circ\text{C}/\text{W}$
	TO-126/TO-126C TO-126S		10	$^\circ\text{C}/\text{W}$

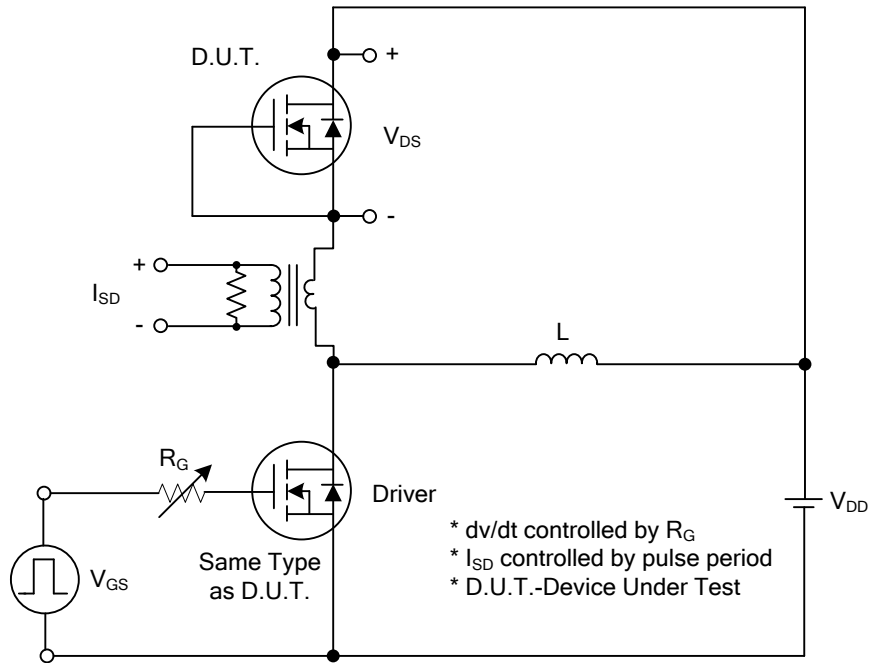
■ **ELECTRICAL CHARACTERISTICS** ( $T_J=25^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	650			V
Drain-Source Leakage Current	$I_{DSS}$	$V_{DS} = 650V, V_{GS} = 0V$			10	$\mu A$
Gate-Source Leakage Current	Forward	$I_{GSS}$			100	nA
	Reverse				-100	nA
Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_J$	$I_D=250\mu A$ , Referenced to $25^{\circ}\text{C}$		0.4		$V/^{\circ}\text{C}$
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS} = 10V, I_D = 1.0A$		3.9	5.0	$\Omega$
<b>DYNAMIC CHARACTERISTICS</b>						
Input Capacitance	$C_{ISS}$	$V_{DS}=25V, V_{GS}=0V,$ $f=1\text{MHz}$		320	370	pF
Output Capacitance	$C_{OSS}$		40	50	pF	
Reverse Transfer Capacitance	$C_{RSS}$		9	12	pF	
<b>SWITCHING CHARACTERISTICS</b>						
Total Gate Charge	$Q_G$	$V_{DS}=520V, V_{GS}=10V,$ $I_D=2.4A$ (Note 1, 2)		45	55	nC
Gate-Source Charge	$Q_{GS}$		4		nC	
Gate-Drain Charge	$Q_{GD}$		8.4		nC	
Turn-On Delay Time	$t_{D(ON)}$	$V_{DD}=325V, I_D=2.4A,$ $R_G=25\Omega$ (Note 1, 2)		35	50	ns
Turn-On Rise Time	$t_R$		40	60	ns	
Turn-Off Delay Time	$t_{D(OFF)}$		130	160	ns	
Turn-Off Fall Time	$t_F$		40	60	ns	
<b>DRAIN-SOURCE DIODE CHARACTERISTICS</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$				2.0	A
Maximum Pulsed Drain-Source Diode Forward Current	$I_{SM}$				8.0	A
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS} = 0V, I_{SD} = 2.0A$			1.4	V
Reverse Recovery Time	$t_{rr}$	$V_{GS} = 0V, I_{SD} = 2.4A,$ $di/dt = 100A/\mu s$ (Note1)		180		ns
Reverse Recovery Charge	$Q_{rr}$		0.72		$\mu C$	

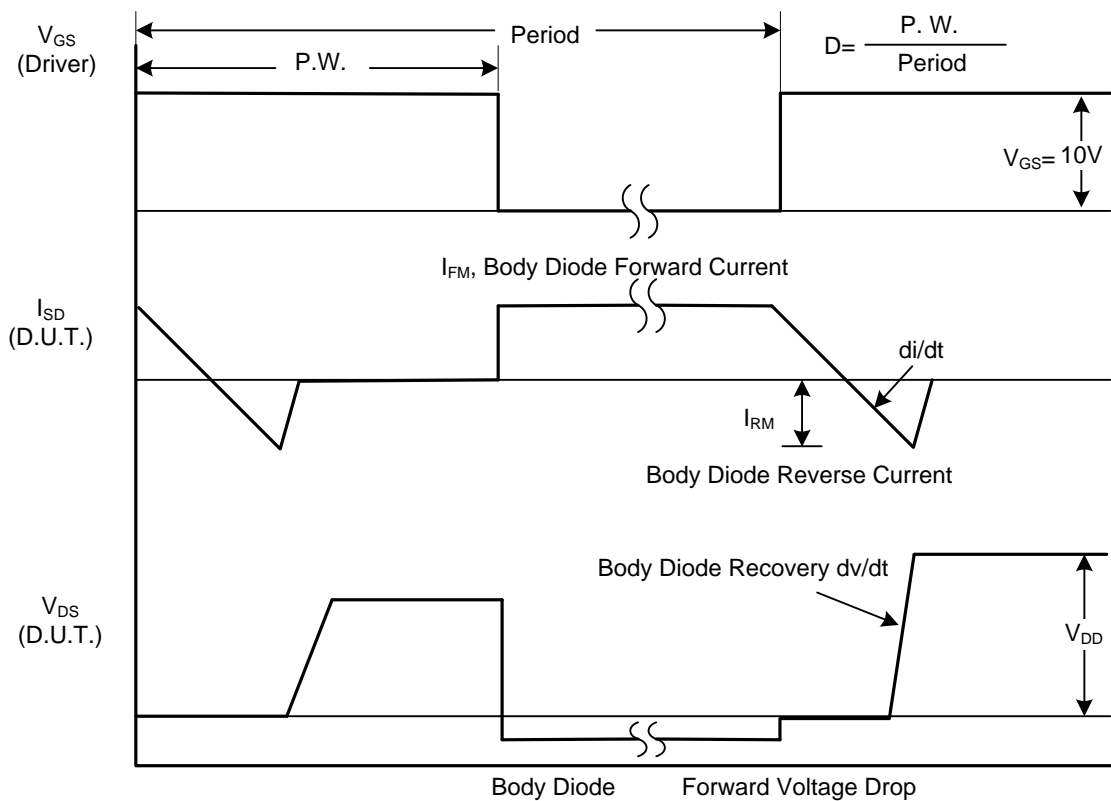
Notes: 1. Pulse Test: Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$ .

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

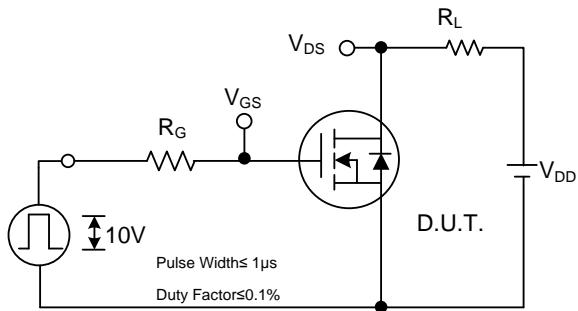


Peak Diode Recovery  $dv/dt$  Test Circuit

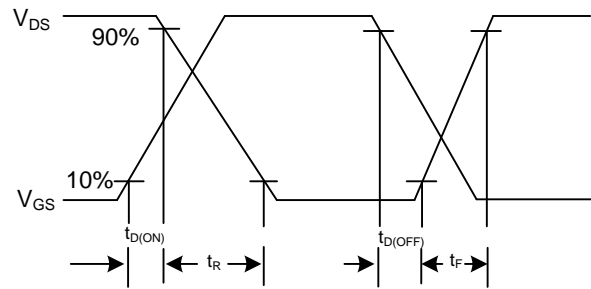


Peak Diode Recovery  $dv/dt$  Waveforms

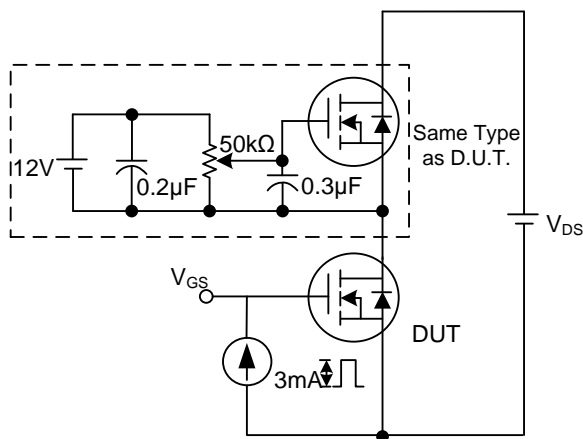
## TEST CIRCUITS AND WAVEFORMS



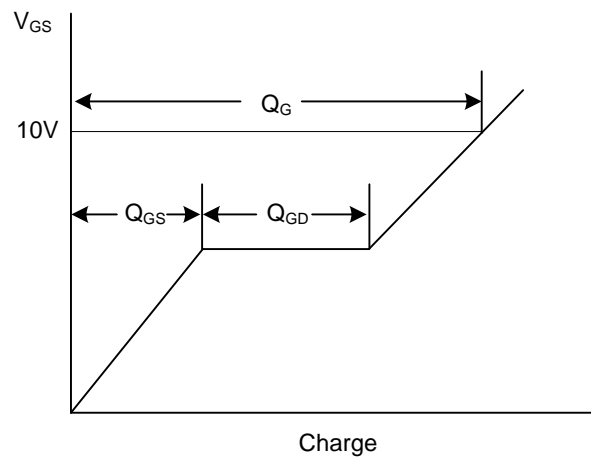
Switching Test Circuit



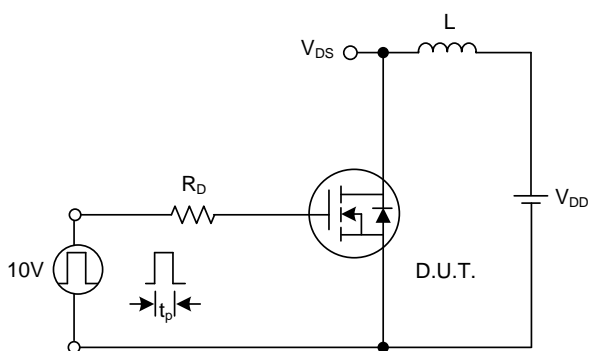
Switching Waveforms



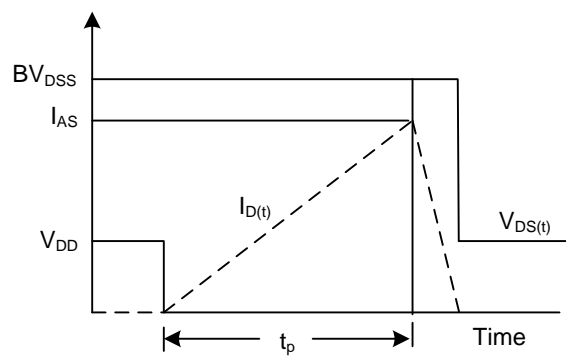
Gate Charge Test Circuit



Gate Charge Waveform

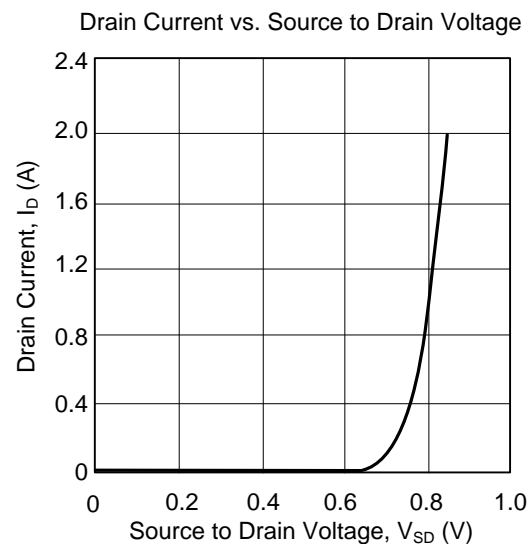
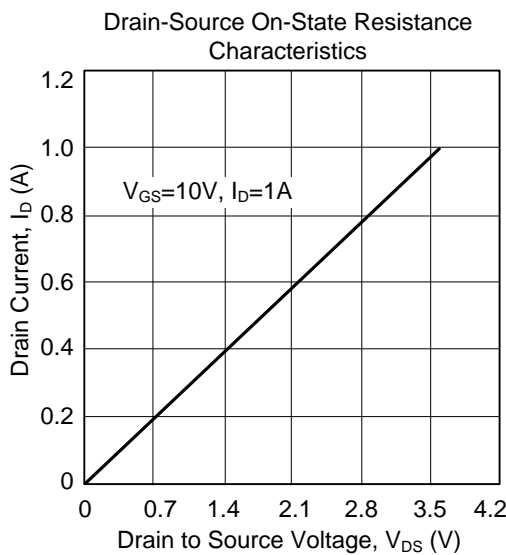
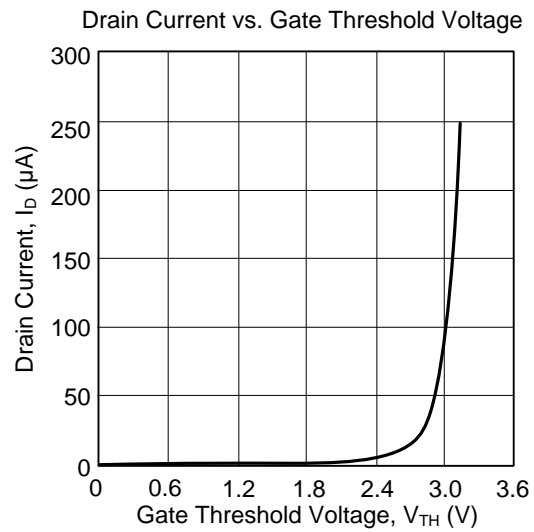
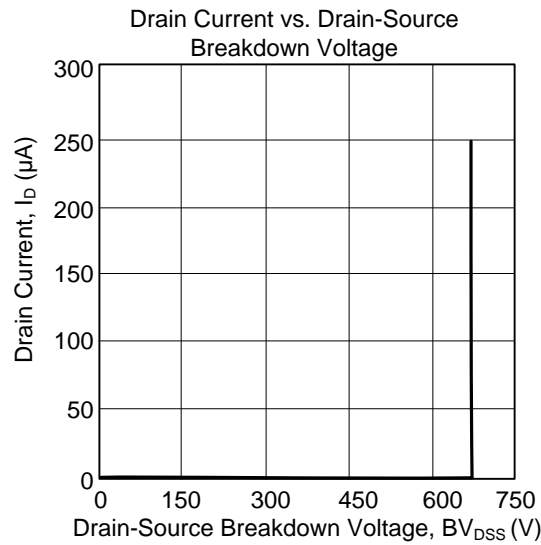


Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

## ■ TYPICAL CHARACTERISTICS



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